

22 October 2015

Product data sheet

1. General description

Unidirectional Transient Voltage Suppressor (TVS) in an ultra small leadless DSN1608-2 (SOD963) package, designed for transient overvoltage protection.

2. Features and benefits

- Rated peak pulse current: I_{PPM} = 80 A (8/20 µs pulse)
- Rated peak pulse power: P_{PPM} = 1200 W (8/20 μs pulse)
- Dynamic resistance $R_{dyn} = 0.06 \Omega$
- Reverse current: I_{RM} = 0.025 μA
- Very low package height: 0.25 mm

3. Applications

- Power supply protection
- Industrial application
- Power management

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{PPM}	peak pulse current	t _p = 8/20 μs	[1][2]	-	-	80	Α
		t _p = 10/1000 μs	[3][2]	-	-	20	Α
V _{RWM}	reverse standoff voltage	T _{amb} = 25 °C		-	-	5	V

- [1] In accordance with IEC 61000-4-5 and IEC 61643-321 (8/20 µs current waveform).
- [2] Measured from pin 1 to pin 2.
- [3] In accordance with IEC 61643-321 (10/1000 µs current waveform).





5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		1 - 2
2	А	anode		sym035
			Transparent top view DSN1608-2 (SOD963)	

6. Ordering information

Table 3. Ordering information

Type number	Package	Je				
	Name	Description	Version			
PTVS5V0Z1USKN	DSN1608-2	leadless ultra small package; 2 terminals; body 1.6 x 0.8 x 0.25 mm	SOD963			

7. Marking

Table 4. Marking codes

Type number	Marking code
PTVS5V0Z1USKN	72

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
P _{PPM}	peak pulse power	t _p = 8/20 μs	[1][2]	-	1200	W
		t _p = 10/1000 μs	[3][2]	-	200	W
I _{PPM}	peak pulse current	t _p = 8/20 μs	[1][2]	-	80	Α
		t _p = 10/1000 μs	[3][2]	-	20	Α
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-40	125	°C
T _{stg}	storage temperature			-65	150	°C
ESD maxim	um ratings					
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	[4][2]	-	30	kV
		IEC 61000-4-2; air discharge	[4][2]	-	30	kV

- 1] In accordance with IEC 61000-4-5 and IEC 61643-321 (8/20 μs current waveform).
- [2] Measured from pin 1 to pin 2.
- [3] In accordance with IEC 61643-321 (10/1000 µs current waveform).
- [4] Device stressed with ten non-repetitive ESD pulses.

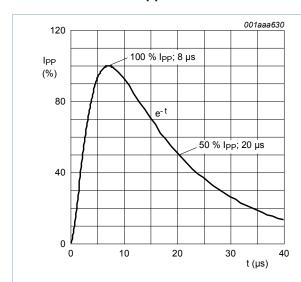


Fig. 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

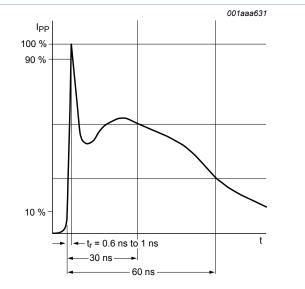
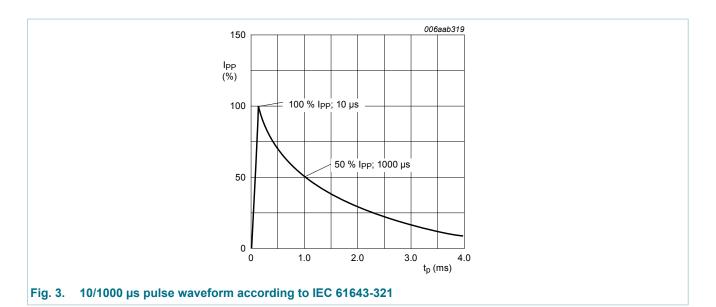


Fig. 2. ESD pulse waveform according to IEC 61000-4-2

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9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{RWM}	reverse standoff voltage	T _{amb} = 25 °C		-	-	5	V
I _{RM}	reverse leakage current	V _R = 5 V; T _{amb} = 25 °C	[1]	-	0.025	1	μΑ
C_d	diode capacitance	f = 1 MHz; V _R = 0 V; T _{amb} = 25 °C		-	1200	-	pF
V_{BR}	breakdown voltage	I _R = 10 mA; T _{amb} = 25 °C	[1]	6.4	7	7.8	V
V_{CL}	clamping voltage	I_{PPM} = 80 A; T_{amb} = 25 °C; t_p = 8/20 µs	[2][1]	-	-	18	V
		I_{PPM} = 20 A; T_{amb} = 25 °C; t_p = 10/1000 µs	[3][1]	-	-	12	V
R _{dyn}	dynamic resistance	I _R = 10 A; T _{amb} = 25 °C	[4][1]	-	0.06	-	Ω

- [1] Measured from pin 1 to 2.
- [2] In accordance with IEC 61000-4-5 and IEC 61643-321 (8/20 µs current waveform).
- [3] In accordance with IEC 61643-321 (10/1000 µs current waveform).
- [4] Non-repetitive current pulse, Transmission Line Pulse (TLP) t_p = 100 ns; square pulse; ANSI / ESD STM5.5.1-2008.

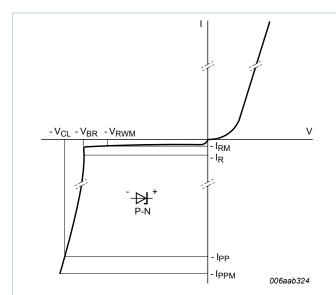


Fig. 4. V-I characteristics for a unidirectional TVS protection diode

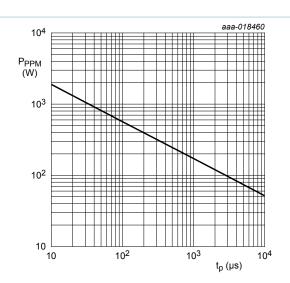


Fig. 5. Rated peak pulse power as a funtion of square pulse duration; typical values

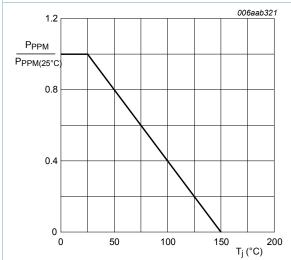


Fig. 6. Relative variation of rated peak pulse power as a function of junction temperature; typical values

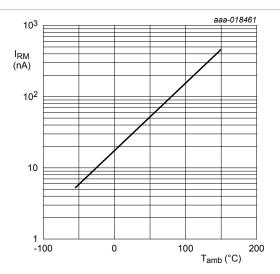
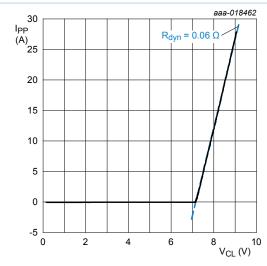
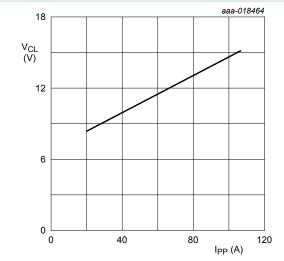


Fig. 7. Relative variation of reverse leakage current as a function of junction temperature; typical values



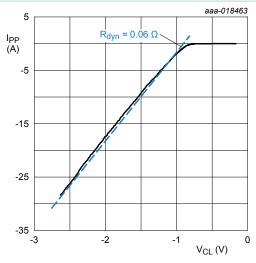
 t_p = 100 ns; Transmission Line Pulse (TLP)

Fig. 8. Dynamic resistance with positive clamping voltage; typical values



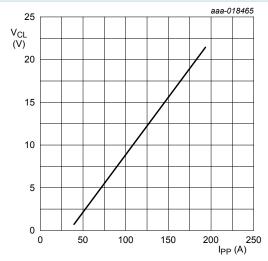
 t_p = 8/20 $\mu s;$ according to IEC 61000-4-5 and IEC 61643-321

Fig. 10. Dynamic resistance with positive clamping voltage; typical values



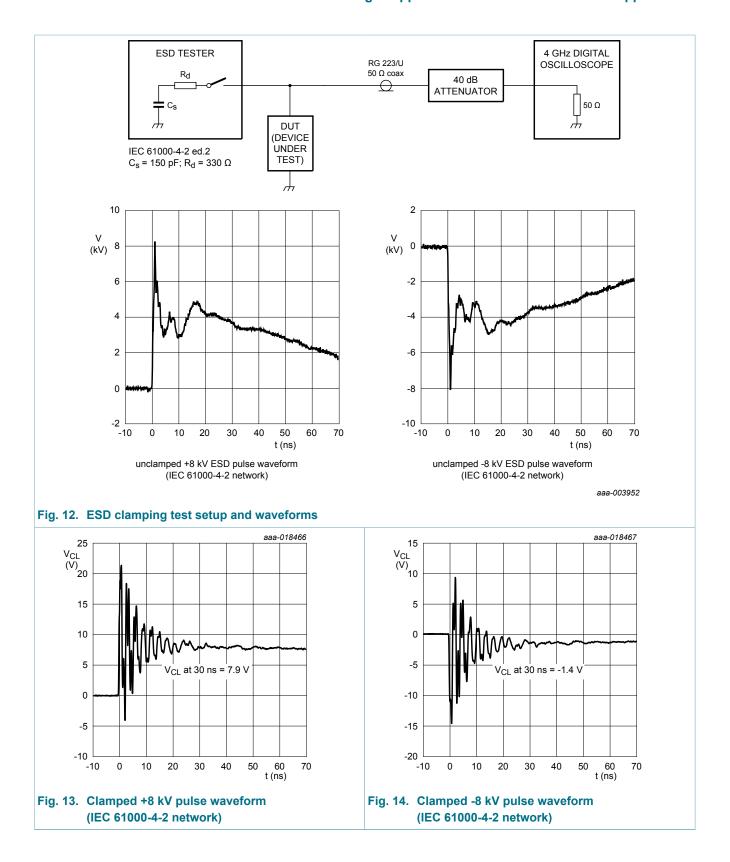
t_p = 100 ns; Transmission Line Pulse (TLP)

Fig. 9. Dynamic resistance with negative clamping voltage; typical values



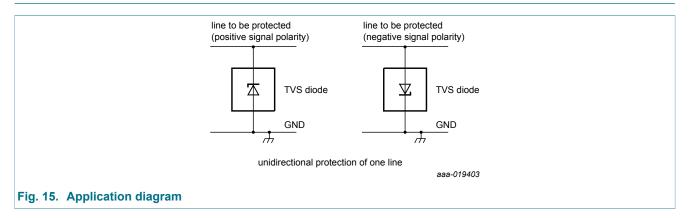
 t_p = 8/20 μ s; according to IEC 61000-4-5 and IEC 61643-321

Fig. 11. Dynamic resistance with negative clamping voltage; typical values

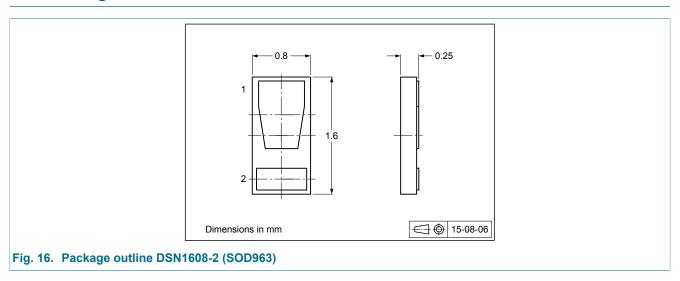


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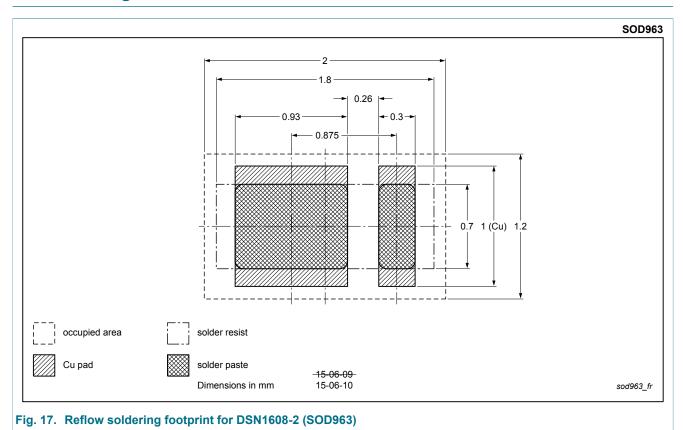
10. Application information



11. Package outline



12. Soldering



13. Revision history

Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PTVS5V0Z1USKN v.2	20151022	Product data sheet	-	PTVS5V0Z1USKN v.1
Modifications:	Section 9. Characte	ristics: diode capacitance	e C _d and clamping voltage	e V _{CL} updated
PTVS5V0Z1USKN v.1	20150604	Preliminary data sheet	-	-

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14.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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